



Ultrathin Hexagonal SnS₂ Nanosheets Coupled with Tetragonal CuInS₂ Nanosheets as 2D/2D Heterojunction Photocatalysts Toward High Visible-Light Photocatalytic Activity and Stability

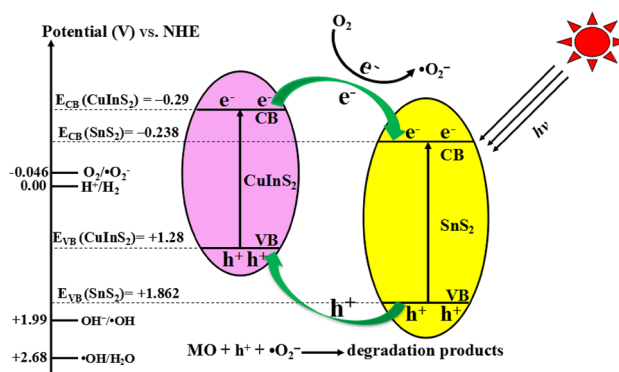
Kai Zhang¹ · Yunhai Zhang² · WanJu Zhang¹

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Abstract

A kind of 2D/2D heterojunction photocatalysts was constructed by a facile in situ hydrothermal method that a tetragonal CuInS₂ nanosheets was horizontal loaded in ultrathin hexagonal SnS₂ nanosheets. Contrasted to pure CuInS₂ and SnS₂ nanosheets, the CuInS₂/SnS₂ nano-heterojunctions revealed a noteworthy improvement photocatalytic activity under visible light irradiation for the degradation of organic dyes, which should be attributed to the narrowest band gap and the efficient charge separation and transfer improving the contact region in heterojunction interface. Especially, with 0.5 wt% addition of CuInS₂, the heterojunction nanosheets shows a supreme visible-light photocatalytic activity and a superb degradation efficiency which reached 99% in 60 min with the solution of methyl orange. Moreover, CuInS₂/SnS₂ nano-heterojunctions deliver excellent reusability in five degradation–regeneration cycles. The results indicated that CuInS₂/SnS₂ has a promising prospect in organic pollutant treatment due to high efficiency and excellent stability.

Graphical Abstract



Keywords CuInS₂/SnS₂ · Heterojunction · In situ hydrothermal method · Visible-light photocatalysis

1 Introduction

A new wave of research activities, the efficient utilization of solar energy, has stimulated by the ever-increasing global demand for energy. Visible-light-driven semiconductor photocatalysts, a promising prospective application in the treatment of environmental pollutants in water, have created widespread interest in the scientific and technology communities [1–5]. However, solar energy conversion efficiency

✉ Yunhai Zhang
wszhyhai@foxmail.com

✉ WanJu Zhang
28813470@qq.com

Extended author information available on the last page of the article

still requires much improvement, although various strategies including bandgap engineering, crystal phase control, and microstructure construction have been employed [6, 7]. Recently, developing heterostructured materials by carefully selecting and coupling two different semiconductors has yielded novel photocatalysts with high activity [8–11].

Metal sulfides are considered promising materials for coupling with other semiconductors, due to their relatively narrow band gap. Among them, tin sulfide (SnS₂) has been attracting increasing attention for its cheap, abundant, and its low band gap (1.91–2.35 eV) as well as it can be designed as an environmental friendly visible-light photocatalyst [12–15]. However, reports showed that its photodegradation performance should be improved [14, 15]. In contrast with single semiconductor, the photocatalysts performance of the two different semiconductors composite can be successful and higher improved, which owns to the narrowest band gap and the efficient charge separation and transfer improving the contact region in heterojunction interface [16–18]. For example, SnS₂/BiOBr heterojunction nanoplates showed higher photocatalytic activity than BiOBr and SnS₂ for the degradation of rhodamine B under visible light irradiation [18]. Recently, Gao et al. achievement illustrated that the photocatalytic activity of SnS₂-based heterojunction could be obviously enhanced by way of extending the photore-sponding range and increasing the charge separation efficiency [19]. Besides, Zhang et al. demonstrated that it is the RhB photodegradation apparent rate constant that under visible light is higher than that of pure g-C₃N₄ and SnS₂ nanosheets by a factor of 4 and 8, respectively [20].

The remarkable properties of narrow band gap, high stability, and strong visible-light absorption made ternary chalcogenide compounds gained tremendous attraction, and a notable candidate for the application of photocatalyst in recent years [21]. Taking Copper indium disulfide (CuInS₂) for example, it is an universal ternary chalcogenide semiconductor that exhibits an excellent photocatalytic property [22–24]. However, the small specific surface area and fast electron–hole recombination have brought a huge obstacle to single CuInS₂ semiconductors for the application of photocatalyst. Besides, the truth that subdued photocatalytic activity would incredible decrease its photocatalytic efficiency during recycling process. Moreover, it can be observed that, among those SnS₂ and copper indium disulfide (CuInS₂), the energy levels of the valence band (VB) and conduction band (CB) can match well between the two, which plays a synergistic effect on and benefits to the transmission of photoinduced charge carriers. Therefore, it can be theoretically find out that the CuInS₂/SnS₂ heterostructure composites can exhibit excellent photocatalytic activity to remove organic pollutant under visible light.

Herein, a 2D/2D heterojunction photocatalysts was constructed by a facile and simple one-step in situ hydrothermal

method, through coupling the tetragonal CuInS₂ nanosheets with ultrathin hexagonal SnS₂ nanosheets. As such, the as-fabricated CuInS₂/SnS₂ heterojunction nanosheets exhibit significant enhancement on the photocatalytic activities for the degradation of organic dyes under visible light irradiation as compared to pure CuInS₂ and SnS₂ nanosheets. The morphology, structure, optical and electrochemical properties were characterized, and the photocatalytic activity of CuInS₂/SnS₂ heterojunctions was tested by photodegrading methyl orange under visible-light irradiation, and the reusability of CuInS₂/SnS₂ was evaluated by five consecutive photocatalytic runs. The relationship between its structure and performance, and the possible photocatalytic mechanism were also proposed.

2 Experimental

2.1 Materials and Chemicals

Tin(IV) chloride pentahydrate (SnCl₄·5H₂O) was purchased from Shanghai Fengxian Chemistry Co., Ltd. (Shanghai, China). Thioacetamide (TAA) and cuprous chloride (CuCl) were attained from Tianjin Chemical Reagent Plant (Tianjin, China). Indium chloride (InCl₃·4H₂O) and methyl orange (MO) were received from Aladdin Chemistry Co. Ltd. (Shanghai, China). Anhydrous ethanol, sodium sulfate (Na₂SO₄) and iso-propyl alcohol (IPA) were obtained from Shantou Xilong Chemical Co., Ltd. (Shantou, China). p-Benzoquinone (BQ) was supplied by Shanghai Crystal Pure Reagent Co., Ltd. (Shanghai, China). Triethanolamine (TEOA) was acquired from Shanghai Chemical Reagent Co., Ltd. (Shanghai, China). All chemicals and solvents were of analytical grade and used without further purification.

2.2 Preparation of CuInS₂/SnS₂ Nano-heterojunction

First, the SnS₂ nanosheets were synthesized by a hydrothermal method. Briefly, 0.02 mmol of SnCl₄·5H₂O and 0.04 mol TAA were added in 40 mL of deionized water. After stirring for 30 min, the above mixture was transferred into a Teflon-lined stainless steel autoclave with a capacity of 50 mL. The autoclave was sealed and heated at heated at 180 °C for 20 h and then was naturally cooled to room temperature. The precipitate filtered and washed with distilled water and ethanol for several times, and then dried in a vacuum oven at 100 °C for 5 h.

CuInS₂/SnS₂ nano-heterojunction was fabricated. First, 0.02 mol of SnCl₄·5H₂O, 0.04 mol TAA were added in 40 mL of deionized water with magnetic stirring marked as solution (A) Then a certain amount CuInS₂ (Cu:In:S = 1:1:2) were added in 20 mL of deionized water under magnetic

stirring marked as solution (B). Finally, adding the solution B to the solution A under magnetic stirring drop by drop. After stirring for 30 min, the above mixture transferred into a Teflon-lined stainless steel autoclave with a capacity of 100 mL. The autoclave was sealed and heated at 180 °C for 20 h and then was naturally cooled to room temperature. After that the product was washed with deionized water and ethanol several times, and then was obtained in a vacuum oven at 100 °C for 5 h. Samples mass ratio of CuInS₂ to SnS₂ were denoted as CuInS₂/SnS₂ (0.1%), CuInS₂/SnS₂ (0.5%), CuInS₂/SnS₂ (1%), CuInS₂/SnS₂ (3%) and CuInS₂/SnS₂ (5%), respectively.

2.3 Characterization Methods

Morphologies of CuInS₂, SnS₂ and CuInS₂/SnS₂ nano-heterojunction were examined by scanning electron microscopy (SEM, KYKY-EM3900M) and transmission electron microscope (TEM, JEM-2010F) and high-resolution transmission electron microscope (HRTEM, JEM-2010F). The crystal phase of the samples was analyzed by X-ray diffraction (XRD). BET surface areas and pore structures were analyzed using a GEMINI VII 2390 surface area and porosity analyzer (Micromeritics, USA). The reflectance spectra of the samples were obtained from a U-3900H scan UV-Vis spectrophotometer (Hitachi, Japan). The photoluminescence (PL) spectra were measured using F-7000 fluorescence spectrophotometer (Hitachi, Japan) with an excitation wavelength of 325 nm, scanning speed of 1200 nm min⁻¹, and the photomultiplier voltage of 700 V.

2.4 Electrochemical Measurement

The photocurrent of pure CuInS₂, SnS₂ and 0.5% CuInS₂/SnS₂ nano-heterojunction were determined by using a Chenhua CHI660C Electrochemical Workstation (Shanghai, China) with a standard three-electrode cell. A standard three-electrode system was composed of CuInS₂, SnS₂ or CuInS₂/SnS₂ film fabricated on FTO conductive glass (an effective area of 1 cm²) as working electrode, KCl-saturated calomel electrode (SCE) as reference electrode, platinum plate as counter electrode, and 0.5 mol L⁻¹ Na₂SO₄ as supporting electrolyte. The applied voltage was 0 V for the FTO working electrode. A 300 W xenon lamp (PLS-SXE300, Beijing Trusttech Co., Ltd. China) with a 400 nm cut off filter (400 nm < λ < 780 nm) was used as the source of visible light.

The flat band potentials of pure CuInS₂, SnS₂ and 0.5% CuInS₂/SnS₂ nano-heterojunction were determined by Mott-Schottky plots using the same standard three-electrode system as the photocurrent test, and the applied potential ranges between -1 and 1 V with the scan frequency of 10 kHz.

Electrochemical impedance spectroscopy (EIS) was measured as the same standard three-electrode system and electrochemical workstation as Mott-schottky test, but the electrolyte solution is the mixture of 0.5 mol L⁻¹ Na₂SO₄, 2.5 mmol L⁻¹ potassium hexacyanoferrate(III) (K₃[Fe(CN)₆]I), and 2.5 mmol L⁻¹ potassium ferrocyanide (K₄Fe(CN)₆·3H₂O).

2.5 Photocatalytic Activity Measurement

In this set of experiments, 0.03 g of pure CuInS₂, SnS₂ or CuInS₂/SnS₂ nano-heterojunction were added in aqueous 100 mL of methyl orange (MO) solution (10 mg L⁻¹). Before the reaction, the suspension was magnetically stirred for 30 min in the dark to reach adsorption-desorption equilibrium. Then the suspension was irradiated by 300 W xenon lamps with a 400 nm cut off filter under magnetic stirring. Every 10 min intervals, 3 mL aliquots were collected from the suspension and immediately centrifuged, and the concentration of MO was analyzed using a 754 UV-Vis spectrometer at 465 nm.

2.6 Regeneration and Reuse of Spent CuInS₂/SnS₂ Nano-heterojunction Photocatalyst

In order to evaluate the stability of pure SnS₂ and 0.5% CuInS₂/SnS₂ nano-heterojunction catalyst, the catalytic reaction was performed for five times using the same sample. After each cycle, the catalyst separated through centrifugation and washed with deionized water and ethanol several times, then dried at about 100 °C for 4 h. The recovered photocatalyst was used in the next cycle under the same condition as above.

3 Results and Discussion

3.1 XRD Analysis

As is shown in Fig. 1, the XRD patterns demonstrated the characterization of CuInS₂, SnS₂ and CuInS₂/SnS₂ composites. It can be observed that the CuInS₂/SnS₂ composite XRD pattern is consistent with those of pure SnS₂ (JGPDs No. 023-0677). The main diffraction peaks at about 2θ = 15.03°, 28.20°, 32.12°, 49.96° and 52.50° could be indexed to the (001), (100), (101), (110) and (111) crystalline planes of tetragonal phase of SnS₂ respectively. While, observing no typical diffraction peak of CuInS₂ in the XRD pattern of CuInS₂/SnS₂ composite, it is possibly owe to the low loading content of CuInS₂.

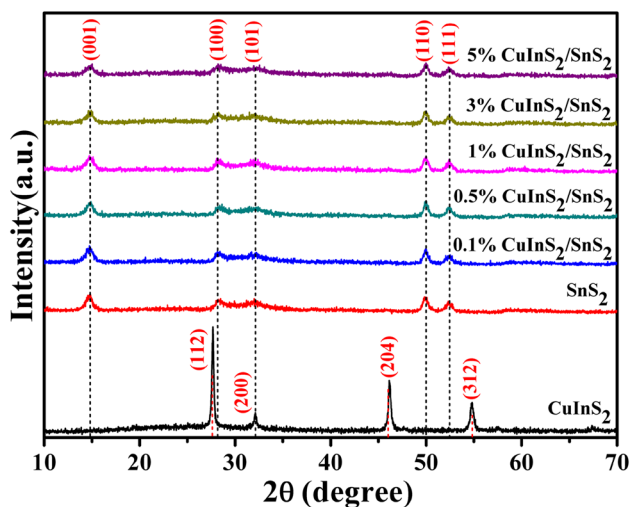


Fig. 1 XRD patterns of pure CuInS₂, pure SnS₂ and CuInS₂/SnS₂ heterojunctions with different CuInS₂ content

3.2 Morphology of Samples

The morphologies of pure SnS₂ and 0.5% CuInS₂/SnS₂ nano-heterojunction were characterized by SEM (Fig. 2). Pure SnS₂ was composed of hierarchically porous and flower-like spheres, and these spheres are constructed by many bending 2D sheets which are densely interconnected with each other to form an entangled architecture with a quantity of pores. Non-uniform network-like spheres with an average diameter of 5–8 μm were clearly observed from the low-magnification SEM image of pure SnS₂ (Fig. 2a). The CuInS₂/SnS₂ composite shows a rough surface and regular hexahedral shape with a size of 50–70 nm (Fig. 2b).

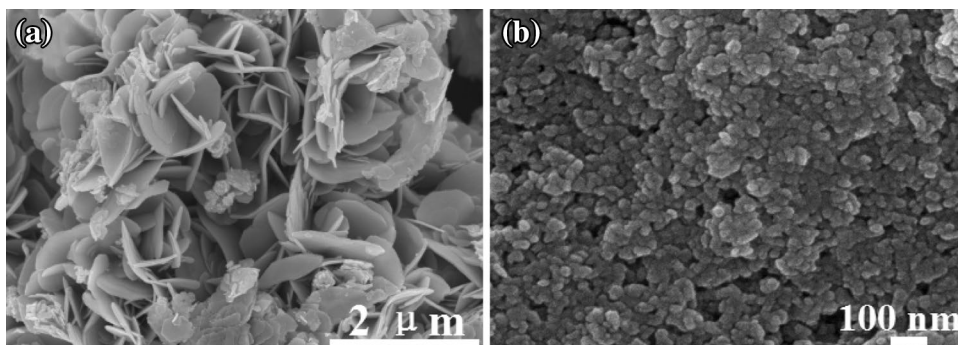
TEM and HRTEM measurements were performed to further characterize the morphology of 0.5% CuInS₂/SnS₂. As shown in Fig. 3a, b, the hexagonal SnS₂ and tetragonal CuInS₂ nano-materials were observed. In addition, as can be seen in Fig. 3c, the measured interplanar spacing is 0.32 nm, it may belong to the CuInS₂ (112) plane or SnS₂ (100) plane. Besides, the SnS₂ (100) and (001) plane

interplanar spacing is 0.32 and 0.59 nm, respectively, which is corresponded to the XRD results.

3.3 XPS Analysis

XPS is an important technique for the detection of variations in chemical composition and oxidation state for materials. Figure 4a shows the survey spectrum of 0.5% CuInS₂/SnS₂ heterojunction. Cu, In, Sn and S elements are present in the survey spectrum of CuInS₂/SnS₂. In addition, the element O (O 1s, 533.14 eV) and C (C 1s, 285 eV) were also observed in the survey spectrum of CuInS₂/SnS₂ due to the organic sulfur precursor and the adventitious hydrocarbon from the XPS instrument itself. Figure 4b–e presented the spectra of Sn 3d, S 2p, Cu 2p and In 3d for CuInS₂/SnS₂ heterojunction. In contrast, the Sn 3d_{5/2} and Sn 3d_{3/2} peaks of SnS₂ nanosheets which appeared at 486.9 and 495.4 eV [25, 26] respectively, are higher than the corresponding binding energy of CuInS₂/SnS₂ heterojunction (Fig. 4b). And, two weak peaks which attributed to the Sn–In bonds are found at the Sn 3d core-level of heterojunction nanosheets [27, 28], further indicating the possible bonding configuration of Sn–In on the heterojunction interface. Meanwhile, the S 2p peaks of SnS₂ nanosheets, reflecting to S–Sn bond [25, 26], are also changed to the high binding energy side, when coupling with CuInS₂ nanosheets. Compared with pure SnS₂, the Sn 3d states of CuInS₂/SnS₂ heterojunction shifted to lower-energy region (Fig. 4b), and the S 2p states of CuInS₂/SnS₂ heterojunction shifted to higher-energy region (Fig. 4c), which indicated the migration of electrons from CuInS₂ to SnS₂ in the CuInS₂/SnS₂ heterojunction [29, 30]. In the CuInS₂/SnS₂ heterojunction, the binding energy of Cu 2p_{3/2}, Cu 2p_{1/2}, In 3d_{5/2} and In 3d_{3/2} located at 932.1, 952.1, 445.1 and 452.5 eV, indicating that the oxidation state of copper and indium are +I and +III, respectively (Fig. 4d, e) [31, 32]. According to the XPS analysis, it can be concluded that CuInS₂/SnS₂ heterojunctions have been successfully fabricated.

Fig. 2 SEM images of a pure SnS₂, b 0.5% CuInS₂/SnS₂ heterojunctions



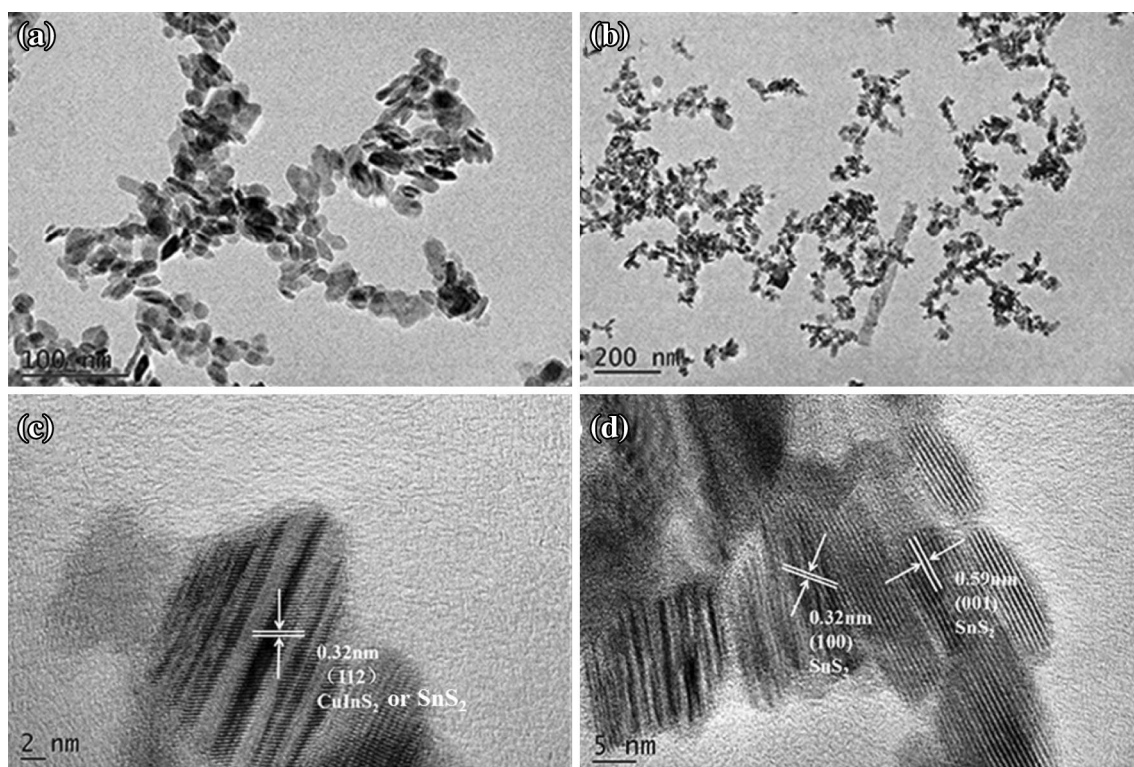


Fig. 3 TEM (a, b) and HRTEM (c, d) images of 0.5% CuInS₂/SnS₂ heterojunctions

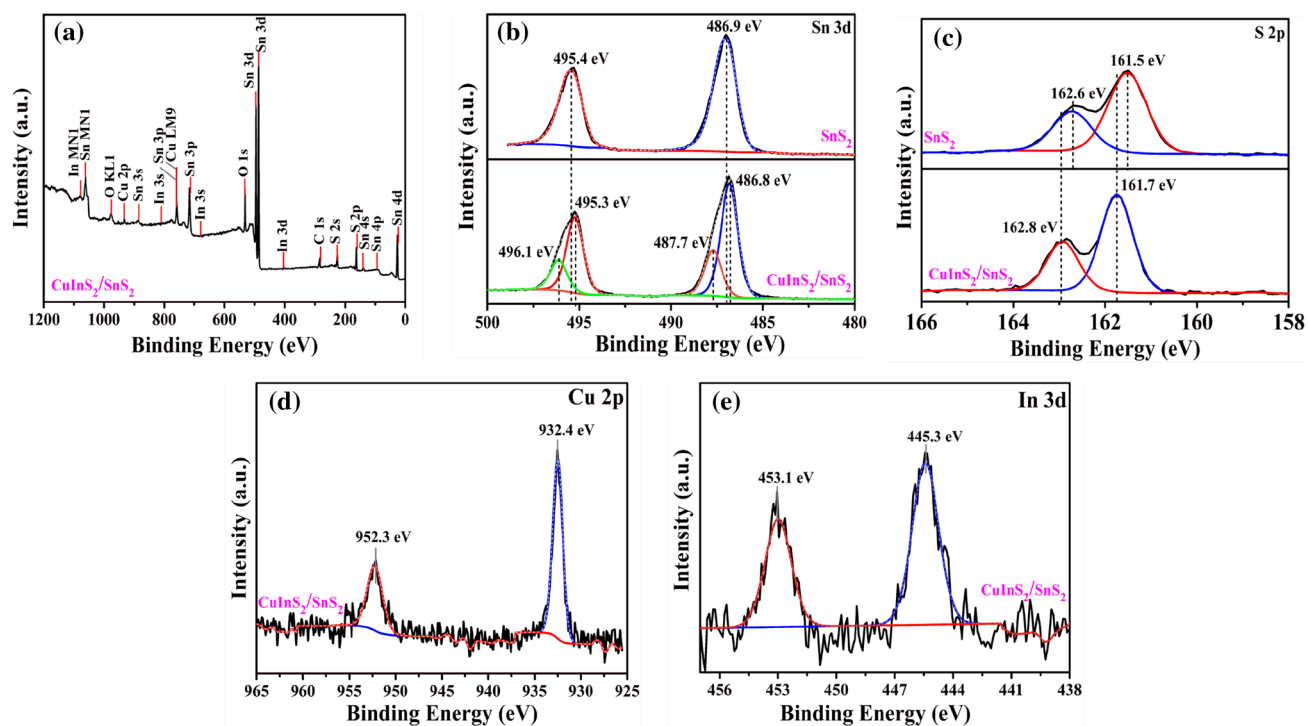


Fig. 4 XPS of a survey spectrum, b Sn 3d, c S 2p, d Cu 2p and e In 3d of pure SnS₂ and 0.5% CuInS₂/SnS₂ heterojunction

3.4 Brunauer–Emmett–Teller Surface Area and Pore Structure

As is depicted in Fig. 5, it was characterized that the N₂ adsorption–desorption isotherms curves of pure SnS₂, CuInS₂ and CuInS₂/SnS₂ nano-heterojunction with different CuInS₂ content. The results demonstrates that it belongs to type IV and H3 hysteresis loop, indicating the existence of mesopores and macro-porous in nano-heterojunction. All the samples showed broad and bimodal pore size distribution with small mesopores (2–4 nm) and larger ones (5–35 nm), further confirming the existence of mesopores. The BET surface area of SnS₂ is 67.9 m² g⁻¹. With increasing CuInS₂ content from 0.1 to 5%, the specific surface area was greatly increased, the BET surface area of CuInS₂/SnS₂ is much higher than that of SnS₂. The main parameters of the samples were listed in Table 1.

3.5 UV–Vis Diffuse Reflectance Spectra

As is shown in Fig. 6, the UV–Vis diffuse reflectance spectra of pure CuInS₂, pure SnS₂ and CuInS₂/SnS₂ heterojunctions with different mass ratio are depicted. Contrasted with pure CuInS₂ and pure SnS₂, the CuInS₂/SnS₂ heterojunctions absorption intensity was enhanced, with the absorption edge shifting to longer wavelength. Moreover, the band gap energies (E_g) of pure CuInS₂, pure SnS₂, and CuInS₂/SnS₂ heterojunctions were calculated by Tauc's equation:

$$(\alpha h\nu)^2 = A(h\nu - E_g)^n \quad (1)$$

where α is absorption coefficient, h is planck's constant, ν is light frequency, A is a constant and E_g is band gap energy, and $n=2$ for direct-band-gap semiconductor and $n=1/2$ for indirect-band-gap semiconductor. The plots of $(\alpha h\nu)^2$ versus $h\nu$ were shown in Fig. 6b, and E_g values were obtained by

Table 1 Physical properties of pure SnS₂, pure CuInS₂ and CuInS₂/SnS₂ heterojunctions

Samples	S _{BET} (m ² g ⁻¹)	Pore volume (cm ³ g ⁻¹)	Average pore size (nm)
SnS ₂	67.9	0.17	10.49
CuInS ₂	32.8	0.18	20.82
0.1% CuInS ₂ /SnS ₂	83.7	0.21	9.27
0.5% CuInS ₂ /SnS ₂	87.5	0.23	10.70
1% CuInS ₂ /SnS ₂	92.7	0.22	9.64
3% CuInS ₂ /SnS ₂	96.6	0.26	10.94
5% CuInS ₂ /SnS ₂	101.3	0.27	10.92

estimating the intercept of the tangent to the plots. The E_g of pure CuInS₂, pure SnS₂, 0.1% CuInS₂/SnS₂, 0.5% CuInS₂/SnS₂, 1% CuInS₂/SnS₂, 3% CuInS₂/SnS₂, and 5% CuInS₂/SnS₂ heterojunctions were estimated to be about 1.57, 2.1, 1.85, 1.91, 1.81, 1.83 and 1.87 eV, respectively.

3.6 Mott–Schottky Analysis

The flat band potentials (V_{fb}) of CuInS₂, SnS₂ and CuInS₂/SnS₂ were calculated according to the Mott–Schottky equation (Fig. 7).

$$\frac{1}{C^2} = \frac{2}{A^2 e \epsilon \epsilon_0 N_A} \left(E - V_{fb} - \frac{k_B T}{e} \right) \quad (2)$$

where C = interfacial capacitance, A = the electrode surface, E = applied potential, ϵ = dielectric constant of the semiconductor, ϵ_0 = permittivity of free space, T = absolute temperature, e = electronic charge, k_B = Boltzmann constant, and N_A = carrier concentration [33]. Hence, V_{fb} values can be obtained when a plot of $1/C^2$ against potential yields a

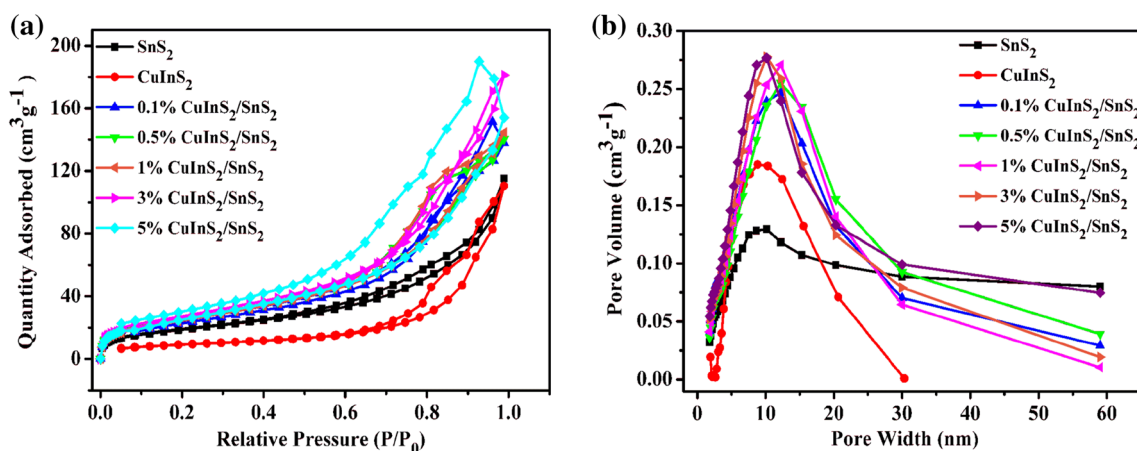


Fig. 5 **a** Nitrogen adsorption–desorption isotherms curves and **b** pore-size distribution curves of pure CuInS₂, pure SnS₂ and CuInS₂/SnS₂ heterojunctions with different CuInS₂ content

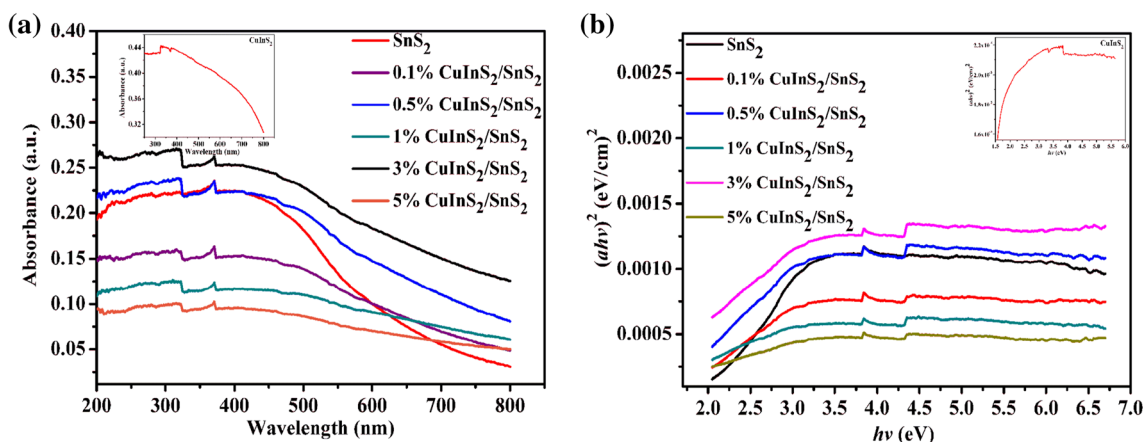


Fig. 6 a UV-Vis diffuse reflectance spectra of pure pure CuInS_2 , pure SnS_2 and $\text{CuInS}_2/\text{SnS}_2$ heterojunctions with different CuInS_2 content and b curves of $(ah\nu)^2$ versus $h\nu$

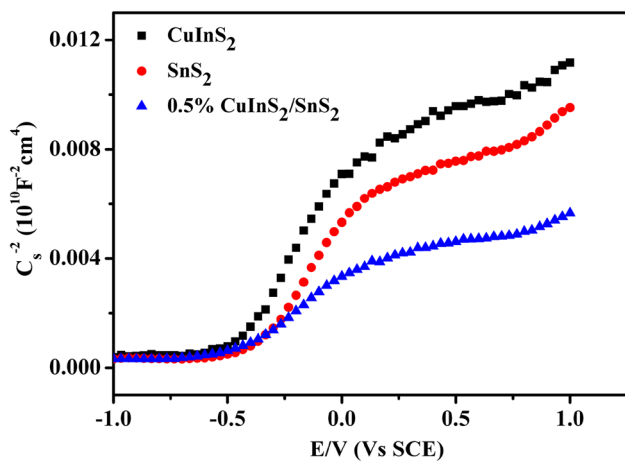


Fig. 7 Mott-Schottky curve of pure CuInS_2 , pure SnS_2 and 0.5% $\text{CuInS}_2/\text{SnS}_2$ heterojunction

straight line. The V_{fb} values of CuInS_2 , SnS_2 , 0.5% $\text{CuInS}_2/\text{SnS}_2$ are -0.538 , -0.48 , and -0.43 eV versus the saturated calomel electrode (SCE), respectively. The positive shift of the flat band potentials is consistent with their photocatalytic activities. Moreover, the slope of Mott-Schottky lines is positive, indicating CuInS_2 , SnS_2 and $\text{CuInS}_2/\text{SnS}_2$ heterojunctions with n-type semiconductor properties.

3.7 Photocurrent Transient and PL Emission Spectra Analysis

The photocurrent transient response test of pure CuInS_2 , pure SnS_2 and 0.5% $\text{CuInS}_2/\text{SnS}_2$ heterojunction upon visible-light irradiation was further carried out and the result is shown in Fig. 8. From the Fig. 8a, with light switching on and off, the photocurrent density exhibits a

rise and decrease promptly, respectively. Obviously, the photocurrent density of 0.5 wt% $\text{CuInS}_2/\text{SnS}_2$ heterojunction was higher than that of pure SnS_2 and CuInS_2 , which suggests that the $\text{CuInS}_2/\text{SnS}_2$ heterojunction is contribute to rapid separation of photogenerated electrons and holes and agreements with its highest photocatalytic activity. For further detecting the photogenerated electrons and holes recombination, PL emission spectra is usually employed. As Fig. 8b manifested, The PL intensity of 0.5 wt% $\text{CuInS}_2/\text{SnS}_2$ heterojunction was lower than that of pure SnS_2 and pure CuInS_2 . The lowest PL intensity of 0.5 wt% $\text{CuInS}_2/\text{SnS}_2$ indicates the most efficient separation of photogenerated electrons and holes. Both PL and photocurrent results confirmed that the outstanding improvement of charge separation in $\text{CuInS}_2/\text{SnS}_2$ heterojunction photocatalysts.

3.8 Nyquist Impedance Analysis

To evaluate the probability photogenic electron and holes compound, Nyquist impedance analysis was further carried out (Fig. 9). The alternating current (AC) impedance spectra are obtained by equivalent circuit simulation as shown in Fig. 9b, where C = electric double layer capacitor, Z_w = Warburg impedance, R_{ct} = charge transfer resistance and R_s = electrolyte resistance, respectively. The total resistance of pure CuInS_2 and SnS_2 is 50 and 296 Ohm, respectively. The total resistance of $\text{CuInS}_2/\text{SnS}_2$ is only 37 Ohm. It is clear to see that the formation of $\text{CuInS}_2/\text{SnS}_2$ heterojunction is able to lead to dramatic decrease in the semicycle arc as compared to pure CuInS_2 and SnS_2 , suggesting a higher charge transfer rate occurred in $\text{CuInS}_2/\text{SnS}_2$ heterojunction electrode. It is consistent with the PL analysis and photocurrent orders.

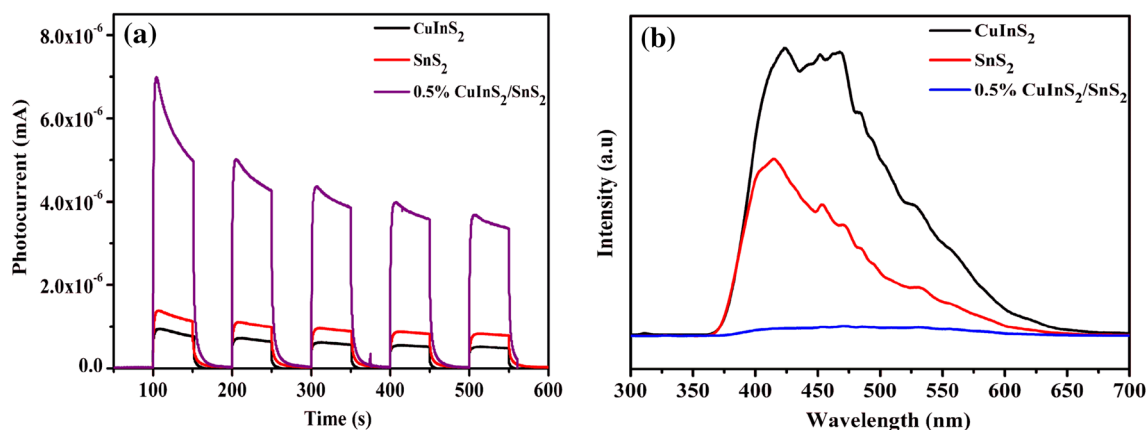
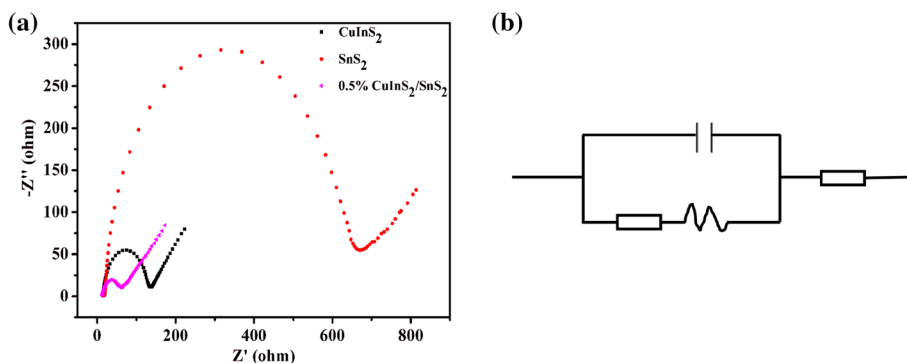


Fig. 8 **a** Photocurrent of pure CuInS₂ pure SnS₂ and 0.5% CuInS₂/SnS₂ heterojunction under visible-light irradiation, **b** PL spectra of pure CuInS₂, SnS₂ and 0.5% CuInS₂/SnS₂ heterojunction

Fig. 9 Electrochemical impedance spectroscopy of the pure CuInS₂, SnS₂ and 0.5% CuInS₂/SnS₂ heterojunction



3.9 The Evaluation of Photocatalytic Activity

3.9.1 Photocatalytic Performance

The visible-light photocatalytic performance of pure CuInS₂, SnS₂ and CuInS₂/SnS₂ heterojunction is displayed in Fig. 10. It was clearly to see from Fig. 10 that the photocatalytic activity of CuInS₂/SnS₂ heterojunction was higher than that of pure CuInS₂. As the amount of CuInS₂ increases, the photocatalytic activity increases gradually and then decreases, the order of degradation rate is 0.5 wt% CuInS₂/SnS₂ > 0.1 wt% CuInS₂/SnS₂ > 1 wt% CuInS₂/SnS₂ > 3 wt% CuInS₂/SnS₂ > SnS₂ > 5 wt% CuInS₂/SnS₂ > CuInS₂. The 0.5% CuInS₂/SnS₂ exhibits the highest photocatalytic activity, which could be attributed to the optimum CuInS₂ content resulting in more efficient generation and transfer of photo-generated electrons and holes at interfaces, but excess CuInS₂ can result in the recombination of photo-generated electrons and holes as well as hinder light absorption.

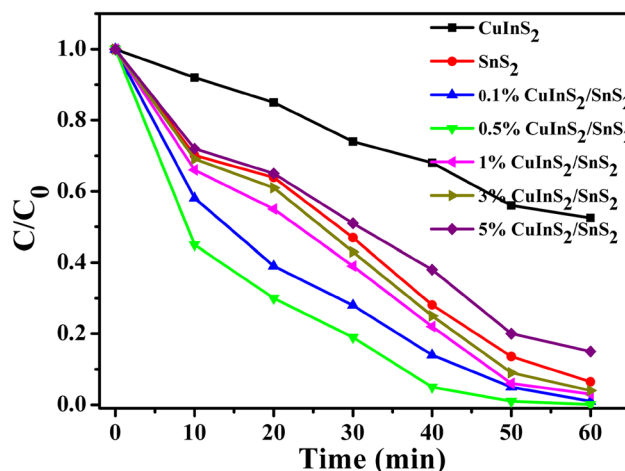


Fig. 10 Photocatalytic activities of pure CuInS₂, pure SnS₂ and CuInS₂/SnS₂ heterojunctions with different CuInS₂ content

3.9.2 Photocatalytic Mechanism

In this part, a tentative photocatalytic reaction mechanism was explored, with IPA ([•]OH quencher), TEOA (h⁺

quencher) and BQ (O_2^- quencher) beeing used and added to the MO solution as scavengers during the MO photodegradation process (Fig. 11). As no quenchers added, the MO degradation efficiency reached 99%; while adding TEOA and BQ separately, the degradation efficiency significantly decreased to 23.38% and 15.68%, respectively. Therefore, it can be concluded that the active species (O_2^- and h^+) have a vital influence on the degradation of MO based on the above results, and the possible photocatalytic mechanism of $\text{CuInS}_2/\text{SnS}_2$ heterojunction is illustrated in Scheme 1. Under visible-light irradiation, both SnS_2 and CuInS_2 can be excited to generate photogenerated electrons (e^-) and holes (h^+). The electrons that excited form CuInS_2 conduction band (CB) can inject into CB of SnS_2 ; besides, the photogenerated holes in VB of SnS_2 have access to transfer easily to the valence band (VB) of CuInS_2 . Therefore, the separation efficiency of photoinduced charge carriers was remarkably improved by the photosynergistic effect of $\text{CuInS}_2/\text{SnS}_2$ heterojunction through the photoinduced interfacial charge transfer reducing the recombination of photogenerated e^- and h^+ . Since the CB levels of CuInS_2 and SnS_2 were more negative than the reduction potential of oxygen $\text{E}(\text{O}_2/\text{O}_2^-)$ (-0.046 V vs. NHE) [34, 35], thus, the photo-generated e^- can react with adsorbed O_2 on the surface of the catalyst to produce O_2^- radicals. Compared with the potential of $\text{OH}^\cdot/\text{H}_2\text{O}$ (2.68 V vs. NHE) and $\text{OH}^\cdot/\text{OH}^-$ (1.99 V vs. NHE) [36], the remained h^+ on the VB of CuInS_2 could not react with OH^- or H_2O generating OH^\cdot radicals because of the lower VB level of CuInS_2 (1.28 V vs. NHE). Subsequently, the highly reactive radical species of O_2^- and h^+ participated in the photodegradation of the MO aqueous solution. The active species trapping experiment results also confirmed that O_2^- and h^+ were the main reactive species, with OH^\cdot beeing the less critical one for the degradation of MO.

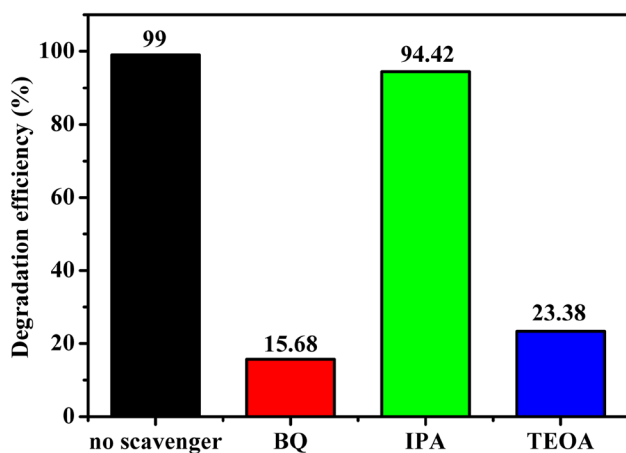
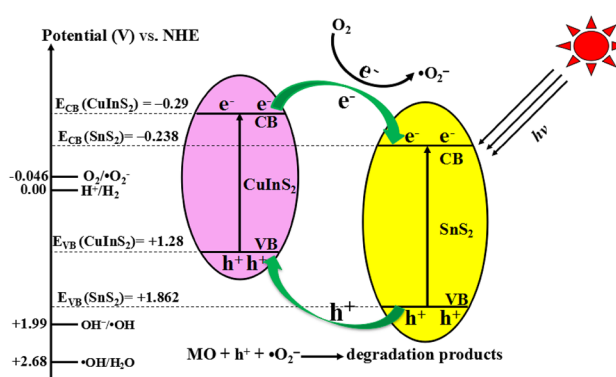


Fig. 11 Effect of different scavengers on the MO photodegradation by 0.5% $\text{CuInS}_2/\text{SnS}_2$ heterojunction



Scheme 1 Schematic illustration for possible photocatalytic mechanism of $\text{CuInS}_2/\text{SnS}_2$ heterojunction under visible-light irradiation

3.10 Photostability of $\text{CuInS}_2/\text{SnS}_2$

The reusability is an important property for practical application. Hence, the photostability of 0.5% $\text{CuInS}_2/\text{SnS}_2$ heterojunction was tested by recycling the photocatalyst for the degradation of MO under visible-light irradiation (Fig. 12). For comparison, the photostability of SnS_2 was also investigated. There is no obviously decline in the photocatalytic degradation efficiency of MO after five degradation–regeneration cycles.

4 Conclusions

$\text{CuInS}_2/\text{SnS}_2$ heterojunctions were constructed by a facile in situ one step hydrothermal method. The visible-light photocatalytic activity of $\text{CuInS}_2/\text{SnS}_2$ heterojunctions was influenced by different CuInS_2 mass ratio. The optimal

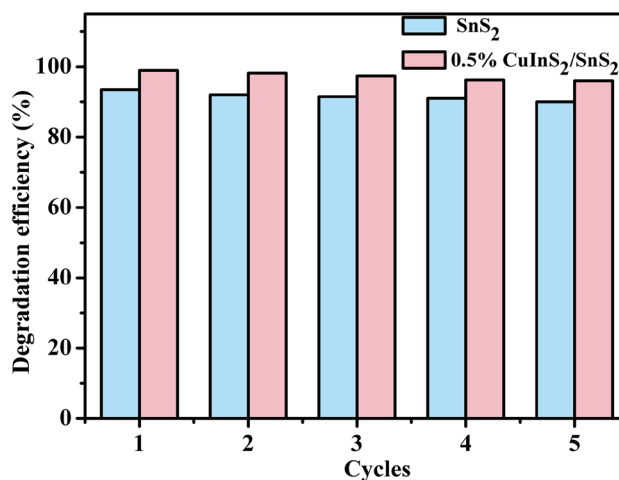


Fig. 12 Reusability of pure SnS_2 and 0.5% $\text{CuInS}_2/\text{SnS}_2$ heterojunction

0.5% CuInS₂/SnS₂ heterojunctions demonstrated the highest visible-light photocatalytic activity, which is almost two times of pure CuInS₂. The 0.5% CuInS₂/SnS₂ showed the most efficient charge separation and transfer, leading to the highest visible-light photocatalytic activity with 99% degradation efficiency of MO in 60 min. Moreover, CuInS₂/SnS₂ heterojunctions show high catalytic stability after five consecutive cycles, which indicating it has a promising prospect in degradation organic pollutant.

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Affiliations

Kai Zhang¹ · Yunhai Zhang² · WanJu Zhang¹

¹ School of Chemistry and Chemical Engineering, Hubei Key Laboratory for Processing and Application of Catalytic Materials, Huanggang Normal University, Huangzhou 438000, China

² Key Laboratory for Magnetism and Magnetic Materials, Key Laboratory of Special Function Materials

and Structure Design of Ministry of Education, Institute of Material Science and Engineering, Lanzhou University, Lanzhou 730000, China